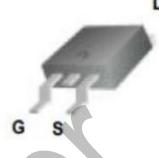
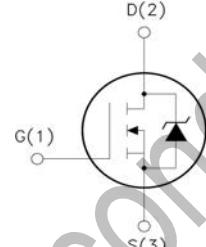


 <b>WGU5N60SE/WGD5N60SE</b>	  <b>TO-251</b>  <b>TO-252</b>  1. Gate (G) 2. Drain (D) 3. Source (S)
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### Absolute Maximum Ratings ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{DSS}$	Drain-Source Voltage	600	V
$I_D$	Drain Current	$T_j=25^\circ\text{C}$	5
		$T_j=100^\circ\text{C}$	3.0
$V_{GSS}$	Gate-Source Voltage	$\pm 30$	V
$E_{AS}$	Single Pulse Avalanche Energy (note1)	128	mJ
$I_{AR}$	Avalanche Current (note2)	5	A
$P_D$	Power Dissipation ( $T_j=25^\circ\text{C}$ )	50	W
$T_j$	Junction Temperature(Max)	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~+150	$^\circ\text{C}$
$TL$	Maximum lead temperature for soldering purpose, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}$	Thermal Resistance,Junction to Case	-	2.5	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance,Junction to Ambient	-	62.5	$^\circ\text{C}/\text{W}$

**Electrical Characteristics** (Ta=25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
BVDSS	Drain-Source Breakdown Voltage	ID=250µA, VGS=0	600	-	-	V
△BVDSS/△TJ	Breakdown Voltage Temperature Coefficient	ID=250µA, Reference to 25°C	-	0.6	-	V/°C
IDSS	Zero Gate Voltage Drain Current	VDS=600V, VGS=0V	-	-	10	µA
		VDS=480V, TJ=125°C			100	
IGSSF	Gate-body leakage Current, Forward	VGS=+30V, VDS=0V	-	-	100	nA
IGSSR	Gate-body leakage Current, Reverse	VGS=-30V, VDS=0V	-	-	-100	
<b>On Characteristics</b>						
VGS(TH)	Date Threshold Voltage	ID=250µA, VDS=VGS	2	-	4	V
RDS(ON)	Static Drain-Source On-Resistance	ID=2A, VGS=10V	-	-	2.3	Ω
<b>Dynamic Characteristics</b>						
Ciss	Input Capacitance	VDS=25V, VGS=0, f=1.0MHz	-	620	-	pF
Coss	Output Capacitance		-	70	-	
Crss	Reverse Transfer Capacitance		-	8	-	
<b>Switching Characteristics</b>						
Td(on)	Turn-On Delay Time	VDD=300V, ID=4A RG=25Ω (Note 3,4)	-	13	35	ns
Tr	Turn-On Rise Time		-	45	100	
Td(off)	Turn-Off Delay Time		-	20	60	
Tf	Turn-Off Rise Time		-	35	80	
Qg	Total Gate Charge	VDS=480V, VGS=10V, ID=4A (Note 3,4)	-	13.3	-	nC
Qgs	Gate-Source Charge		-	3.4	-	
Qgd	Gate-Drain Charge		-	7.1	-	
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
Is	Max. Diode Forward Current	-	-	-	5	A
ISM	Max. Pulsed Forward Current	-	-	-	20	
VSD	Diode Forward Voltage	ID=4A	-	-	1.4	V
Trr	Reverse Recovery Time	Is=4A, VGS =0V diF/dt=100A/µs (Note3)	-	390	-	nS
Qrr	Reverse Recovery Charge		-	1.5	-	µC

Notes : 1, L=25mH, IAS=4A, VDD=50V, RG=25Ω, Starting TJ =25°C

2, Repetitive Rating : Pulse width limited by maximum junction temperature

3, Pulse Test : Pulse Width ≤ 300µs, Duty Cycle ≤ 2%

4, Essentially Independent of Operating Temperature

## Typical Characteristics

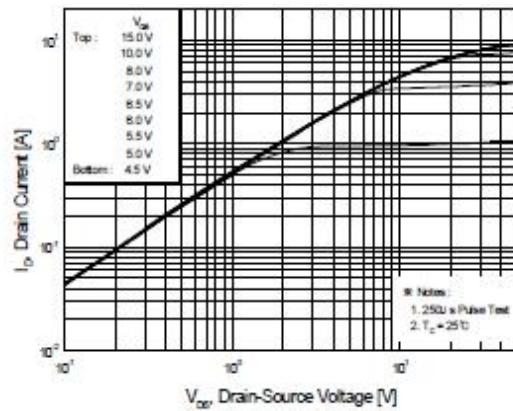


Figure 1. On-Region Characteristics

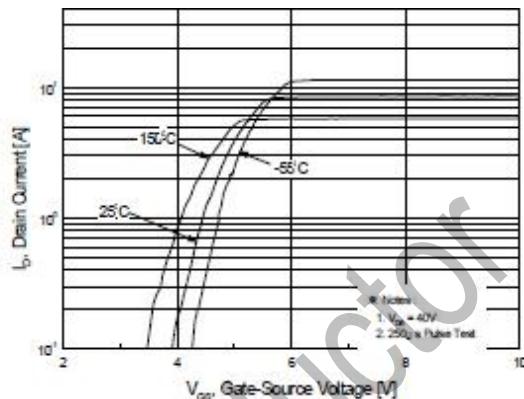


Figure 2. Transfer Characteristics

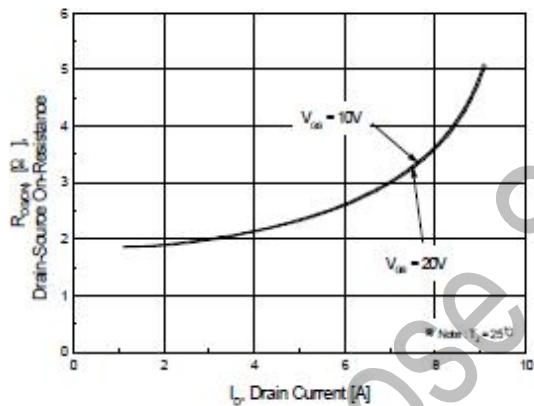


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

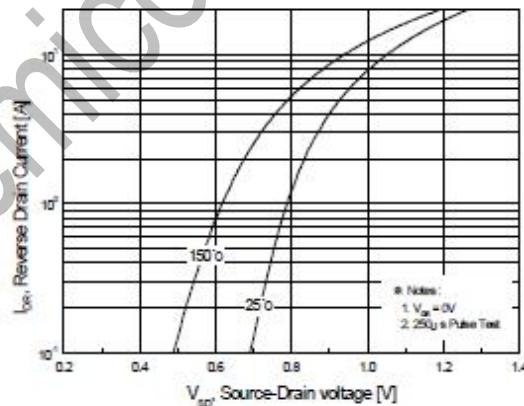


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

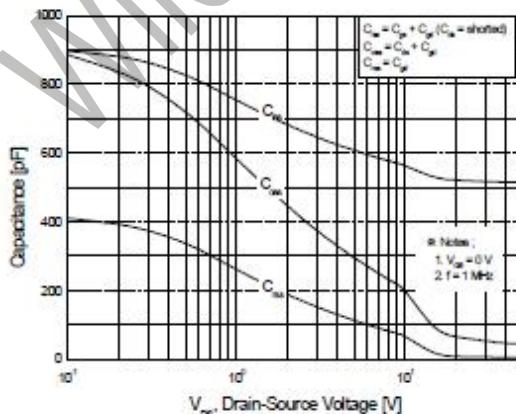


Figure 5. Capacitance Characteristics

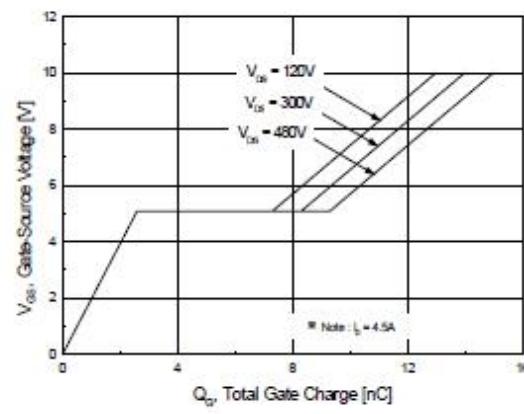
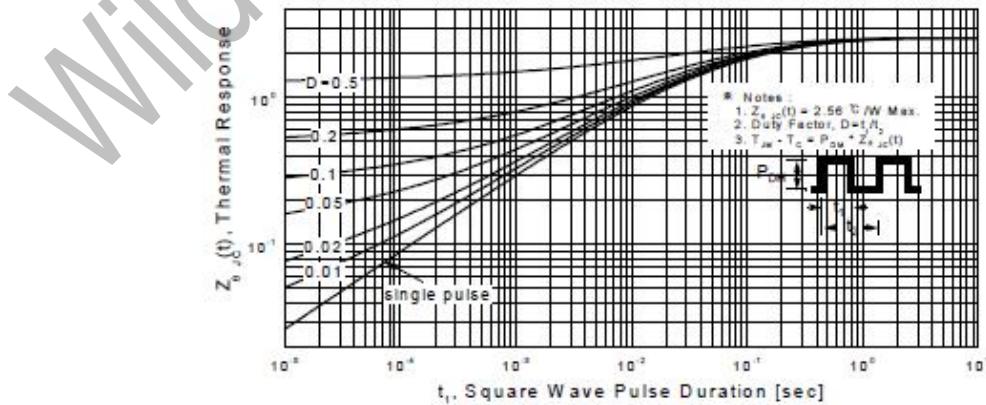
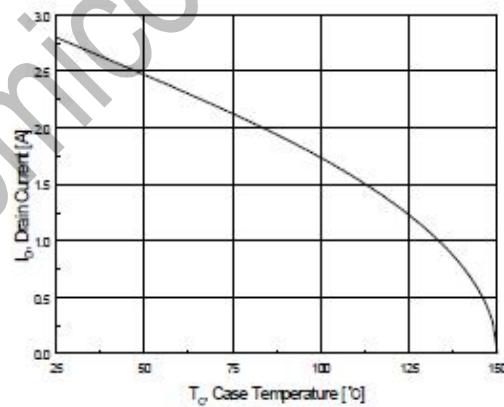
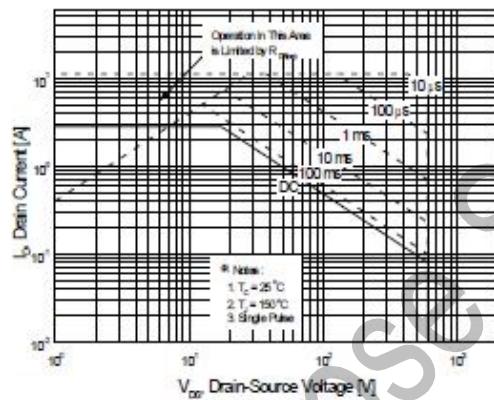
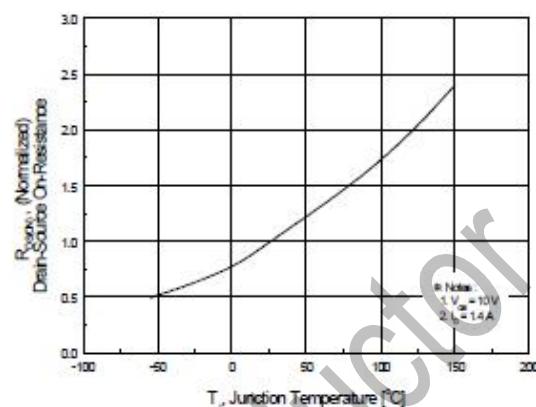
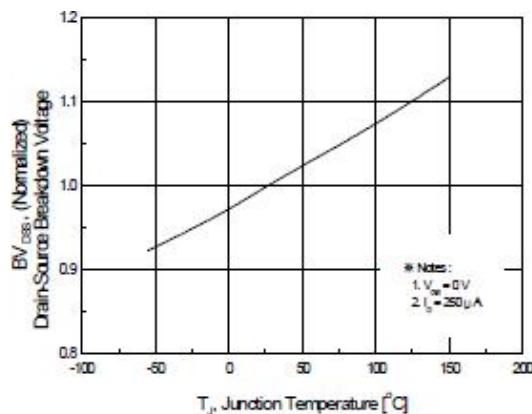
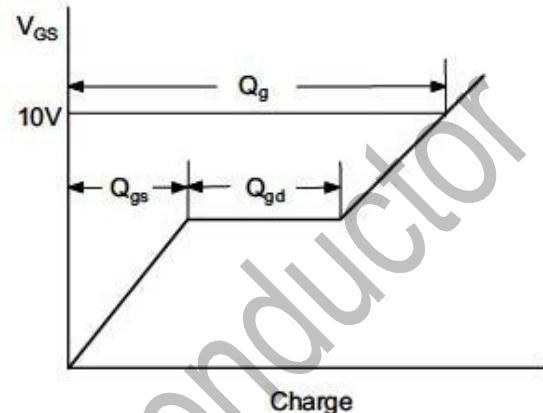
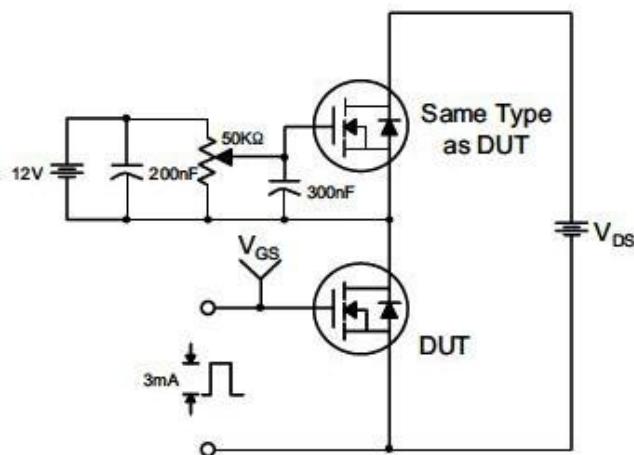


Figure 6. Gate Charge Characteristics

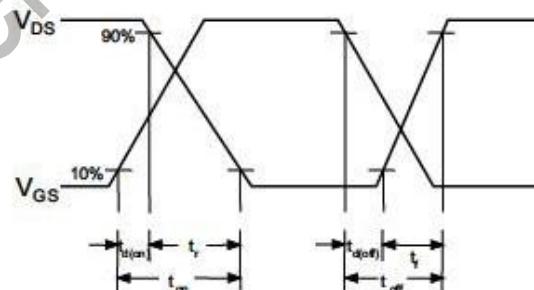
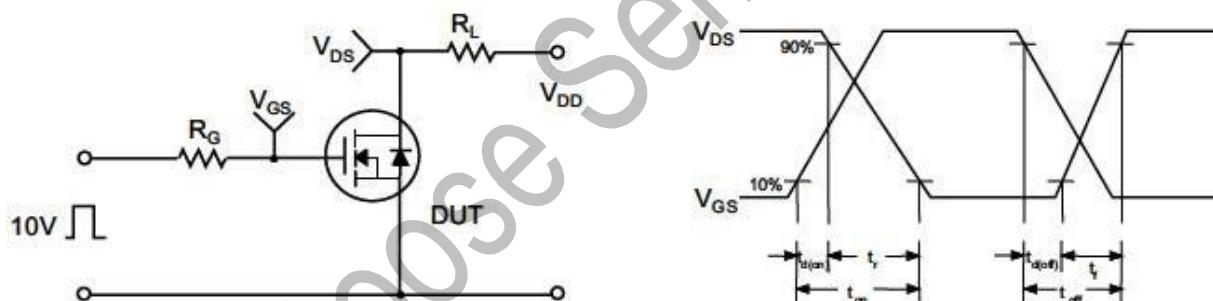
## Typical Characteristics (Continued)



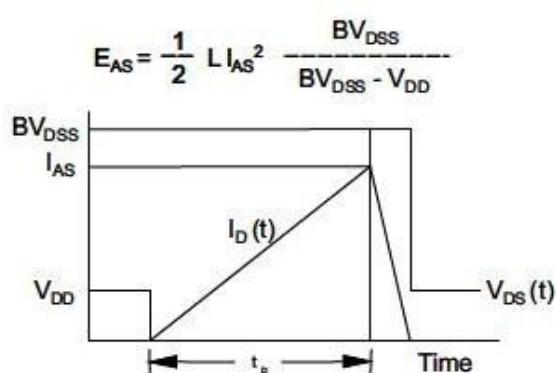
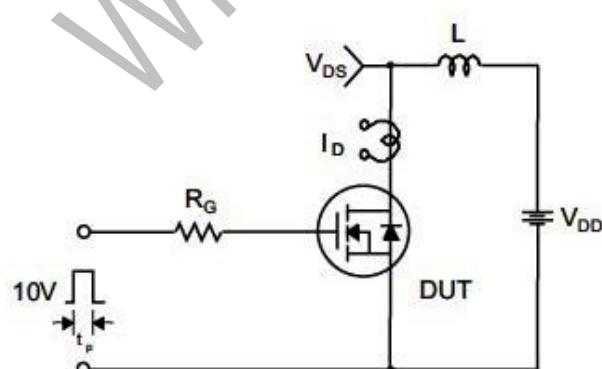
Gate Charge Test Circuit &amp; Waveform



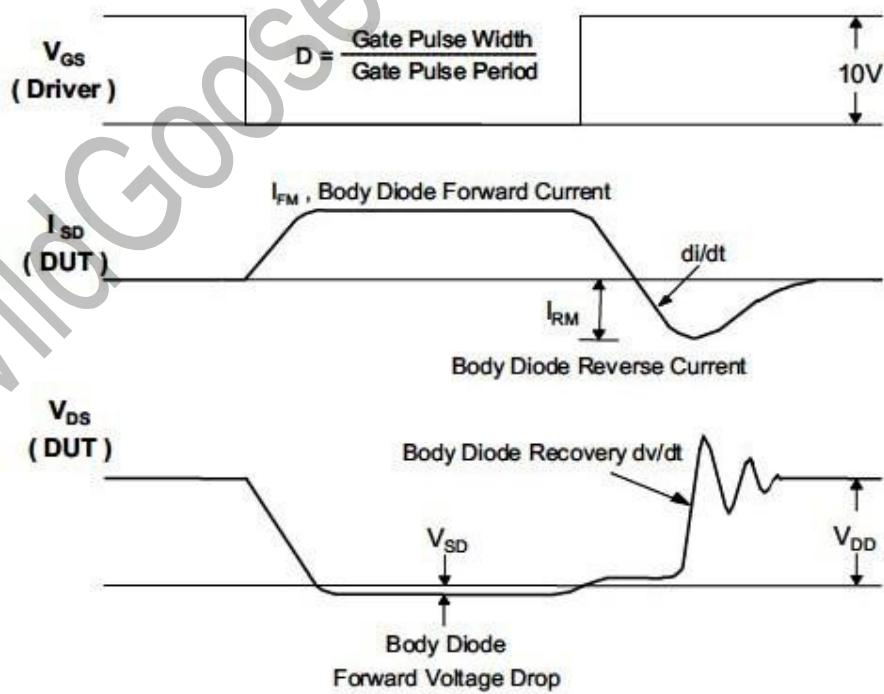
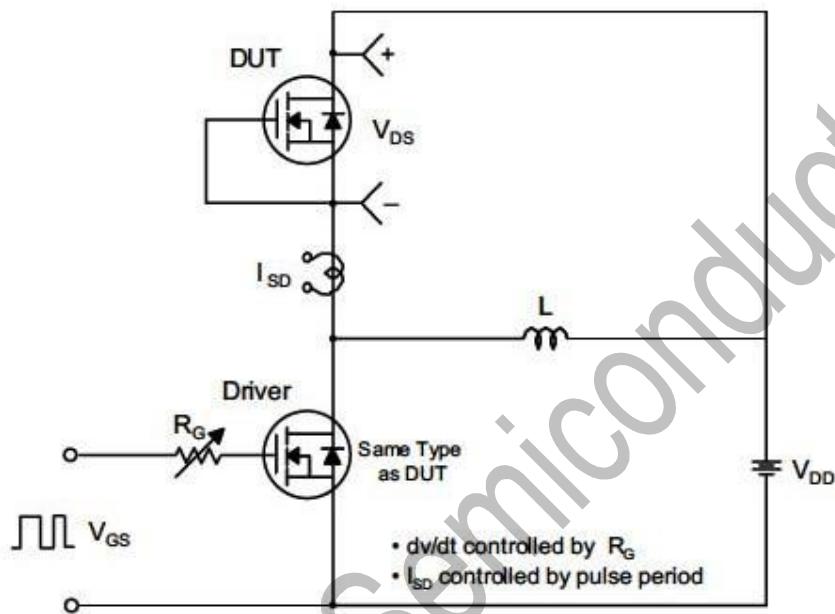
Resistive Switching Test Circuit &amp; Waveforms



Unclamped Inductive Switching Test Circuit &amp; Waveforms



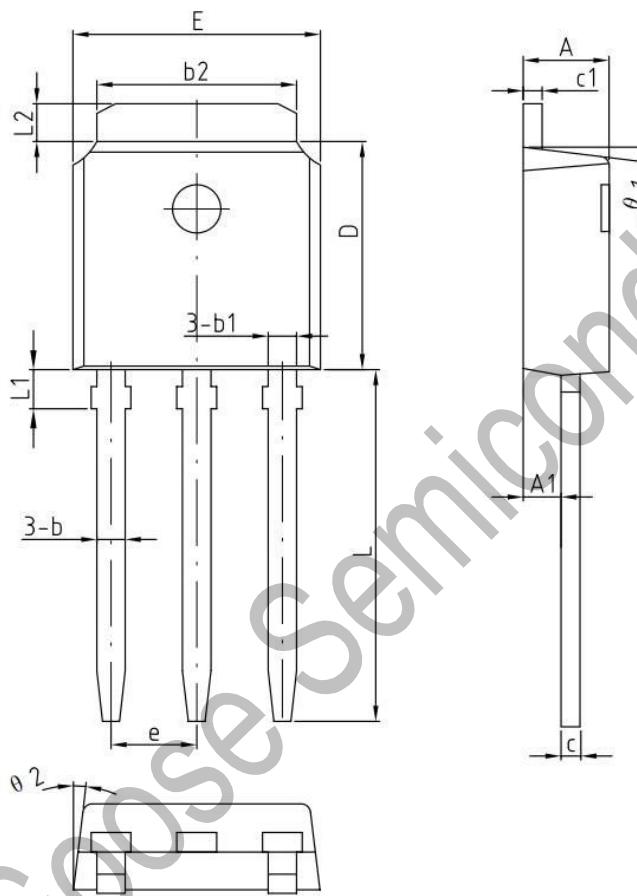
## Peak Diode Recovery dv/dt Test Circuit &amp; Waveforms



**Package Dimension**

TO-251

Unit: mm



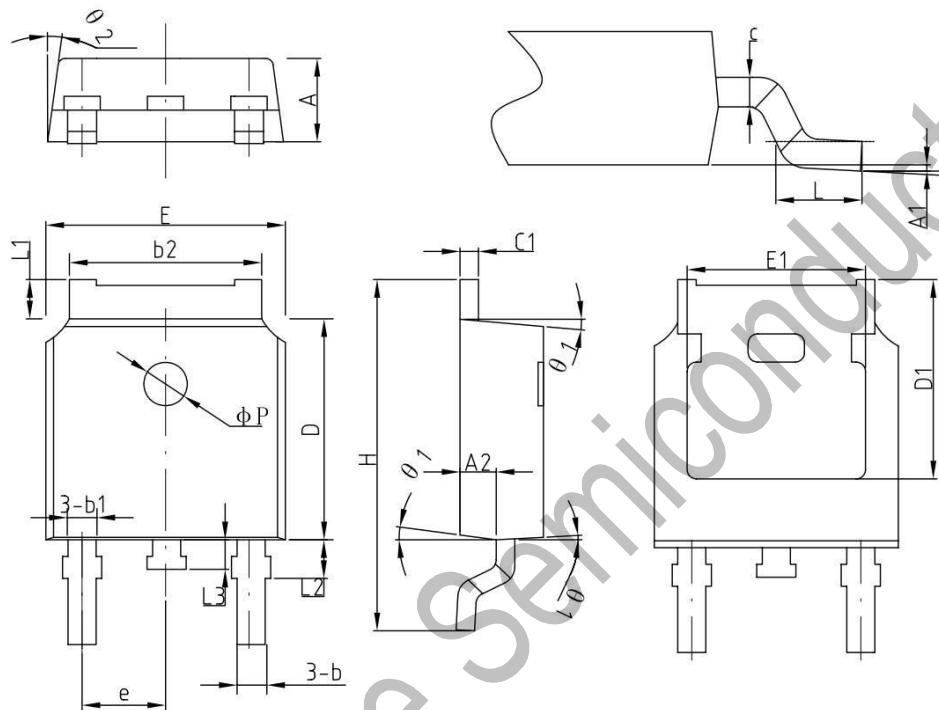
COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	2.2	2.30	2.38
A1	0.90	1.01	1.10
b	0.71	0.76	0.86
b1	—	0.76	—
b2	5.13	5.33	5.46
c	0.46	0.50	0.60
c1	0.46	0.50	0.60
D	6.00	6.10	6.20
E	6.50	6.60	6.70
e	2.286BSC		
L	9.10	9.40	9.70
L1	1.05		
L2	0.90	—	1.25
$\theta_1$	7°		
$\theta_2$	7°		

**Package Dimension**

TO-252

Units: mm

COMMON DIMENSIONS  
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	2.2	2.30	2.38
A1	0	—	0.10
A2	0.90	1.01	1.10
b	0.71	0.76	0.86
b1		0.76	
b2	5.13	5.33	5.46
c	0.47	0.50	0.60
c1	0.47	0.50	0.60
D	6.0	6.10	6.20
D1	—	5.30	—
E	6.50	6.60	6.70
E1	—	4.80	—
e	2.286BSC		
H	9.70	10.10	10.40
L	1.40	1.50	1.70
L1	0.90	—	1.25
L2		1.05	
L3		0.8	
phi_P		1.2	
theta	0°	—	8°
theta_1	5°	7°	9°
theta_2	5°	7°	9°